Reseiptodate: 0/9/20/2006 10596280 - GAyler1792 SEP 2 0 2006 FORM PTO-1449 Application No. 以.S. Department of Commerce Atty. Docket No. Patent and Trademark Office P30037 10/596,280 Applicant INFORMATION STATEMENT Yasuo FUKUDA et al. BY APPLICANT (Use several sheets if necessary) Filing Date Group June 8, 2006 **U.S. PATENT DOCUMENTS EXAMINER** FILING DATE DATE NAME CLASS **SUBCLASS** IF APPROPRIATE INITIAL **DOCUMENT NUMBER** /G.N.R. SUZUKI 7 1 9 08/22/00 /G.N.R./ 6 2 7 7 6 5 7 08/21/01 NOZAWA et al. /G.N.R./ 6 2 3 9 0 4 5 05/29/01 TANAKA et al. **FOREIGN PATENT DOCUMENTS** TRANSLATION **DOCUMENT NUMBER** COUNTRY DATE **CLASS SUBCLASS** YES NO /G.N.R./ 9 0 9 7 9 07/22/97 **JAPAN** /G.N.R./ 2000 1 2 4 03/31/00 **JAPAN** 9 0 /G.N.R./ 2 **JAPAN** Х 8 6 2 0 03/31/95 /G.N.R./ 2000 3 1 7 1 01/28/00 **JAPAN** 0 /G.N.R./ 2002 7 6 12/05/02 W.I.P.O 0 4 OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, Etc.) Semiconductor Silicon Crystal Technology, "VLSI Handbook," Academic Press; 1985, pages 125-/G.N.R./ 128, including a partial English translation. DATE CONSIDERED 01/15/2009 /G. Nagesh Rao/ (01/15/2009) **EXAMINER** *EXAMINER: Initial if citation considered, whether or not citation is in conformance with MPEP 609; draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

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